REVISIONS			
LTR	DESCRIPTION	DATE	APPROVED
B	Convert to military drawing format. Add to vendor CAGE 27014 for device type 01. Editorial changes throughout.	10 DEC 86	
C	Inactivate device type 01 case outline E for new design. Editorial changes on pages 6 and 9. Change code ident. no. to 67268. Editorial changes.	2 NOV. 87	

CURRENT CAGE CODE 67268

REV																												
PAGE																												
REV STATUS OF PAGES	REV	C	C	B	B	C	C	C	B	C	B	B	C	C														
	PAGES	1	2	3	4	5	6	7	8	9	10	11	12	13														

Defense Electronics Supply Center
Dayton, Ohio

Original date of drawing:
17 October 1984

AMSC N/A

PREPARED BY: Jeffery Sunstall

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APPROVED BY: Mike Hauck

SIZE: A

CODE IDENT. NO.: 14933

REV C

MILITARY DRAWING

This drawing is available for use by all Departments and Agencies of the Department of Defense

TITLE: MICROCIRCUITS, DIGITAL, HIGH SPEED CMOS, FLIP-FLOPS, MONOLITHIC SILICON

DWG NO. 84073

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5962-E522

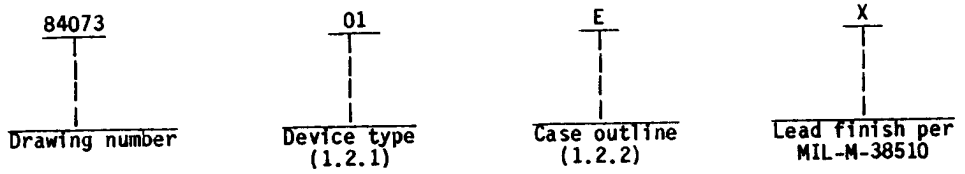
DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

DESC FORM 193
MAY 86

1. SCOPE

1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".

1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 Device type. The device type shall identify the circuit function as follows:

Device type	Generic number	Circuit function
01	54HC174	Hex D-type flip-flops with clear

1.2.2 Case outlines. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter	Case outline
E	D-2 (16-lead, 1/4" x 7/8"), dual-in-line package
F	F-5 (16-lead, 1/4" x 3/8"), flat package
2	C-2 (20-terminal, .350" x .350"), square chip carrier package

1.3 Absolute maximum ratings. 1/

Supply voltage range	-0.5 V dc to +7.0 V dc
DC input voltage	-0.5 V dc to V_{CC} +0.5 V dc
DC output voltage	-0.5 V dc to V_{CC} +0.5 V dc
Clamp diode current	±20 mA
DC output current (per pin)	±25 mA
DC V_{CC} or GND current (per pin)	±50 mA
Storage temperature range	-65°C to +150°C
Maximum power dissipation, (P_D)	500 mW 2/
Lead temperature (soldering, 10 seconds)	+260°C
Thermal resistance, junction-to-case (θ_{JC}):	
Cases E, F, and 2	See MIL-M-38510, appendix C
Junction temperature (T_J)	+175°C

1.4 Recommended operating conditions.

Supply voltage (V_{CC})	+2.0 V dc to +6.0 V dc
Case operating temperature range (T_C)	-55°C to +125°C
Input rise or fall time:	
V_{CC} = 2.0 V dc	0 to 1000 ns
V_{CC} = 4.5 V dc	0 to 500 ns
V_{CC} = 6.0 V dc	0 to 400 ns

1/ Unless otherwise specified all voltages are referenced to ground.
2/ For T_C = +100°C to +125°C, derate lineraly at 12 mW/°C.

Maximum operating frequency (f_{MAX}):

T_C = +25°C	
V_{CC} = 2.0 V dc	5 MHz
V_{CC} = 4.5 V dc	27 MHz
V_{CC} = 6.0 V dc	31 MHz
T_C = -55°C, +125°C	
V_{CC} = 2.0 V dc	3 MHz
V_{CC} = 4.5 V dc	18 MHz
V_{CC} = 6.0 V dc	20 MHz

Minimum removal time clear to clock (t_{REM}):

T_C = -55°C, +125°C	
V_{CC} = 2.0 V dc	100 ns
V_{CC} = 4.5 V dc	20 ns
V_{CC} = 6.0 V dc	17 ns
T_C = -55°C, +125°C	
V_{CC} = 2.0 V dc	150 ns
V_{CC} = 4.5 V dc	30 ns
V_{CC} = 6.0 V dc	26 ns

Minimum setup time, data to clock (t_s):

T_C = +25°C	
V_{CC} = 2.0 V dc	100 ns
V_{CC} = 4.5 V dc	20 ns
V_{CC} = 6.0 V dc	17 ns
T_C = -55°C, +125°C	
V_{CC} = 2.0 V dc	150 ns
V_{CC} = 4.5 V dc	30 ns
V_{CC} = 6.0 V dc	26 ns

Minimum hold time clock to data (t_h):

T_C = +25°C	
V_{CC} = 2.0 V dc	25 ns
V_{CC} = 4.5 V dc	5 ns
V_{CC} = 6.0 V dc	5 ns
T_C = -55°C, +125°C	
V_{CC} = 2.0 V dc	40 ns
V_{CC} = 4.5 V dc	8 ns
V_{CC} = 6.0 V dc	7 ns

Minimum pulse width, clear (t_w):

T_C = +25°C	
V_{CC} = 2.0 V dc	90 ns
V_{CC} = 4.5 V dc	18 ns
V_{CC} = 6.0 V dc	15 ns
T_C = -55°C, +125°C	
V_{CC} = 2.0 V dc	135 ns
V_{CC} = 4.5 V dc	27 ns
V_{CC} = 6.0 V dc	23 ns

Maximum input rise and fall time (t_r, t_f):

T_C = +25°C	
V_{CC} = 2.0 V dc	1000 ns
V_{CC} = 4.5 V dc	500 ns
V_{CC} = 6.0 V dc	400 ns
T_C = -55°C, +125°C	
V_{CC} = 2.0 V dc	1000 ns
V_{CC} = 4.5 V dc	500 ns
V_{CC} = 6.0 V dc	400 ns

2. APPLICABLE DOCUMENTS

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510 - Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883 - Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.

3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.

3.2.2 Truth table. The truth table shall be as specified on figure 2.

3.2.3 Logic diagram. The logic diagram shall be as specified on figure 3.

3.2.4 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.

3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full recommended case operating temperature range.

3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.

TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions 1/ $-55°C \le T_C \le +125°C$ unless otherwise specified		Group A subgroups	Limits Min	Limits Max	Unit
High level output voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL} $\lvert I_O \rvert \le 20$ µA	$V_{CC} = 2.0$ V	1, 2, 3	1.9		V
			$V_{CC} = 4.5$ V		4.4		
			$V_{CC} = 6.0$ V		5.9		
		$V_{IN} = V_{IH}$ or V_{IL} $\lvert I_O \rvert \le 4.0$ mA	$V_{CC} = 4.5$ V		3.7		
		$V_{IN} = V_{IH}$ or V_{IL} $\lvert I_O \rvert \le 5.2$ mA	$V_{CC} = 6.0$ V		5.2		
Low level output voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL} $\lvert I_O \rvert \le 20$ µA	$V_{CC} = 2.0$ V	1, 2, 3		0.1	V
			$V_{CC} = 4.5$ V			0.1	
			$V_{CC} = 6.0$ V			0.1	
		$V_{IN} = V_{IH}$ or V_{IL} $\lvert I_O \rvert \le 4.0$ mA	$V_{CC} = 4.5$ V			0.4	
		$V_{IN} = V_{IH}$ or V_{IL} $\lvert I_O \rvert \le 5.2$ mA	$V_{CC} = 6.0$ V			0.4	
High level input voltage 2/	V_{IH}		$V_{CC} = 2.0$ V	1, 2, 3	1.5		V
			$V_{CC} = 4.5$ V		3.15		
			$V_{CC} = 6.0$ V		4.2		
Low level input voltage 2/	V_{IL}		$V_{CC} = 2.0$ V	1, 2, 3		0.3	V
			$V_{CC} = 4.5$ V			0.9	
			$V_{CC} = 6.0$ V			1.2	
Input capacitance	C_{IN}	$V_{IN} = 0$ V See 4.3.1c	$T_C = +25°C$	4		10	pF
Quiescent current	I_{CC}	$V_{CC} = 6.0$	$V_{IN} = V_{CC}$ or GND	1, 2, 3		160	µA
Input leakage current	I_{IN}	$V_{CC} = 6.0$	$V_{IN} = V_{CC}$ or GND	1, 2, 3		±1	µA
Functional tests		See 4.3.1d		7			

See footnotes at end of table.

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions 1/ $-55°C < T_C < +125°C$ unless otherwise specified		Group A subgroups	Limits Min	Limits Max	Unit
Propagation delay time clock or clear to output (see figure 4)	t_{PHL} t_{PLH}	T_C = +25°C, C_L = 50 pF ±10%	V_{CC} = 2.0 V	9		165	ns
			V_{CC} = 4.5 V			33	
3/			V_{CC} = 6.0 V			28	
		T_C = -55°C +125°C, C_L = 50 pF ±10%	V_{CC} = 2.0 V	10,11		250	ns
			V_{CC} = 4.5 V			50	
			V_{CC} = 6.0 V			43	
Transition delay time, output rise and fall 4/ (see figure 4)	t_{THL} t_{TLH}	T_C = +25°C, C_L = 50 pF ±10%	V_{CC} = 2.0 V	9		75	ns
			V_{CC} = 4.5 V			15	
			V_{CC} = 6.0 V			13	
		T_C = -55°C +125°C, C_L = 50 pF ±10%	V_{CC} = 2.0 V	10,11		110	ns
			V_{CC} = 4.5 V			22	
			V_{CC} = 6.0 V			19	

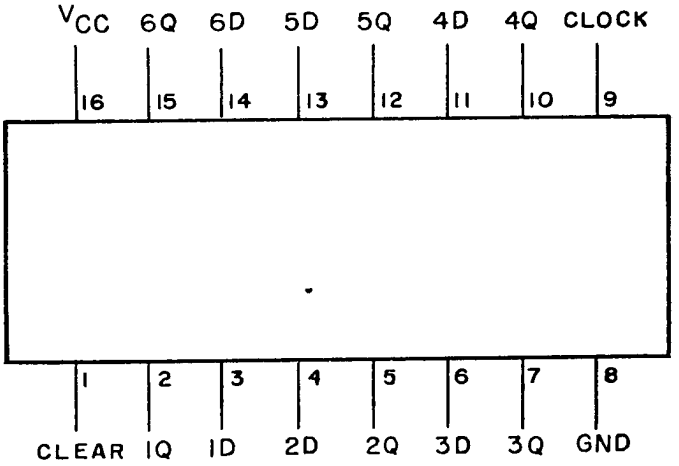
1/ For a power supply of 5 V ±10%, the worst case output voltages (V_{OH} and V_{OL}) occur for HC at 4.5 V. Thus, the 4.5 V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5 V and 4.5 V, respectively. (The V_{IH} value at 5.5 V is 3.85 V.) The worst case leakage current (I_{IN}, and I_{CC}) occur for CMOS at the higher voltage so the 6.0 V values should be used. Power dissipation capacitance (C_{PD}), typically 162 pF, determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

2/ V_{IH} and V_{IL} tests are not required if applied as a forcing function for V_{OH} and V_{OL}.

3/ All testing at V_{CC} = 2.0 V and V_{CC} = 6.0 V shall be guaranteed, if not tested, to the specified parameters.

4/ Transition times, if not tested, shall be guaranteed to the specified limits.

Cases E and F



Case 2

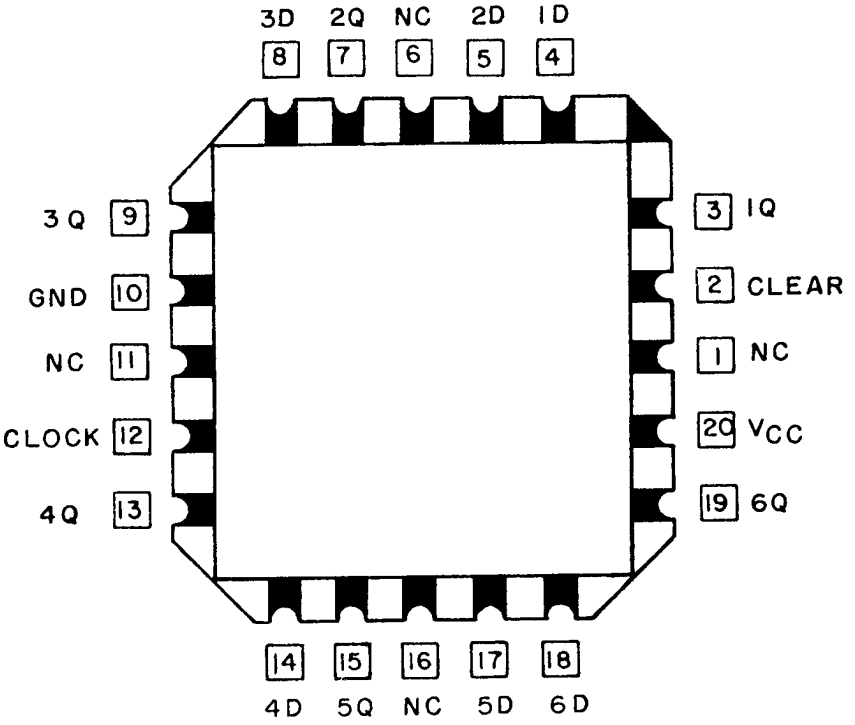


FIGURE 1. Terminal connections (top view).

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Inputs			Outputs
Clear	Clock	D	Q
L	X	X	L
H	↑	H	H
H	↑	L	L
H	L	X	Q_0

H = High level (steady-state)
L = Low level (steady-state)
X = Don't care
↑ = Transition from low to high level
Q_0 = The level of Q before the indicated steady-state input conditions were established

FIGURE 2. Truth table.

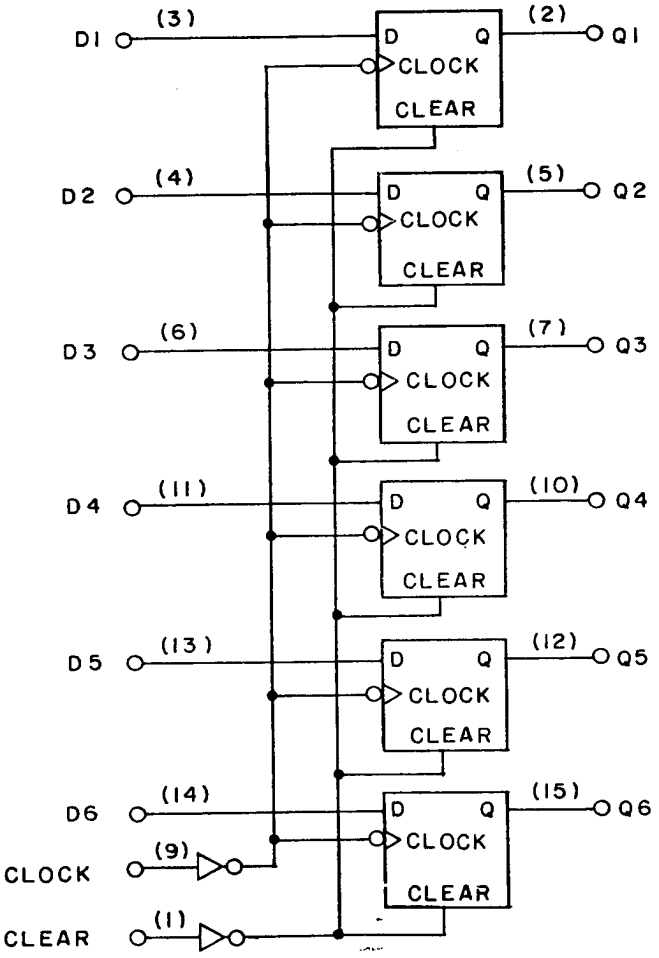

FIGURE 3. Logic diagram.

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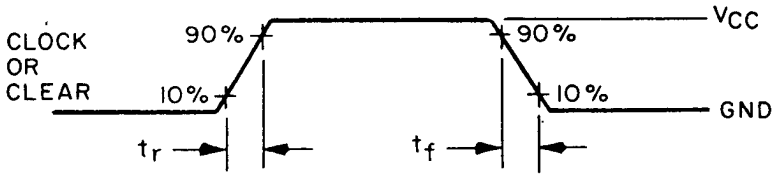

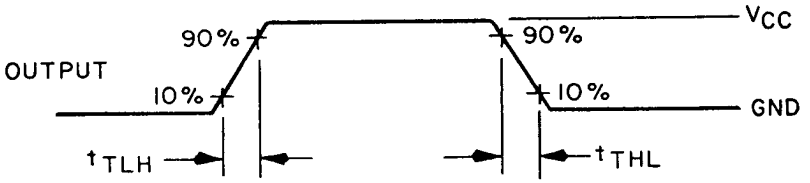

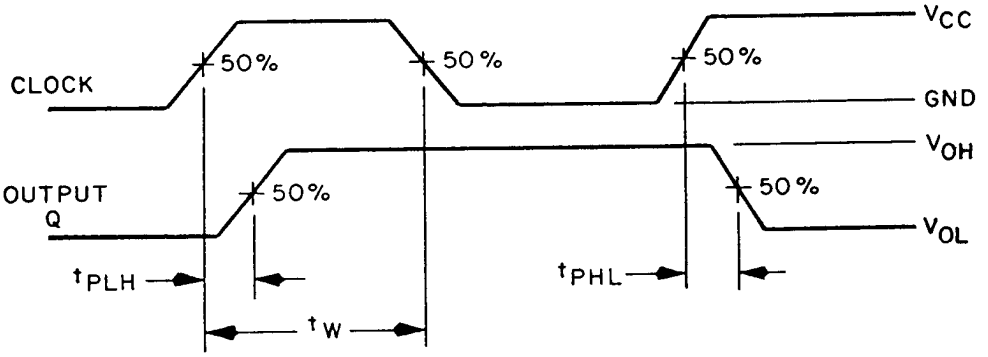

FIGURE 4. Switching waveforms.

MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO	SIZE A		DWG NO. 84073
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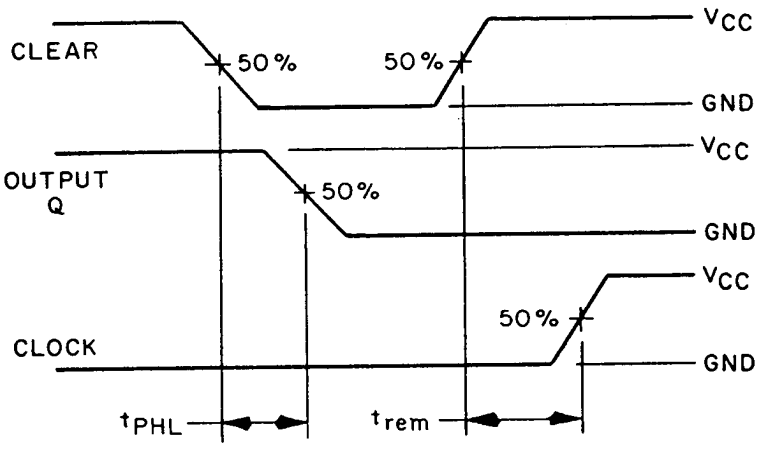

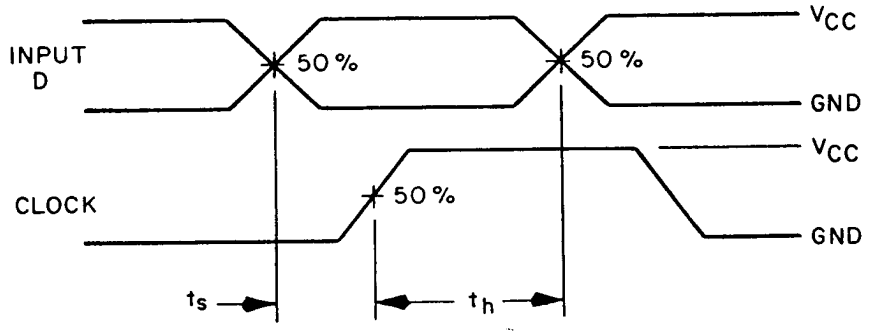

FIGURE 4. Switching waveforms - Continued.

3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.

3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).

3.8 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

4. QUALITY ASSURANCE PROVISIONS

4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).

4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

a. Burn-in test (method 1015 of MIL-STD-883).

(1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).

(2) T_A = +125°C, minimum.

b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

a. Tests shall be as specified in table II herein.

b. Subgroups 5, 6, and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.

c. Subgroup 4 (C_{IN} measurement) shall be measured only for the initial test and after process or design changes which may affect input capacitance.

d. Subgroup 7 tests sufficient to verify the truth table.

4.3.2 Groups C and D inspections.

a. End-point electrical parameters shall be as specified in table II herein.

b. Steady-state life test (method 1005 of MIL-STD-883) conditions:

(1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).

(2) T_A = +125°C, minimum.

(3) Test duration: 1,000 hours, except as permitted by appendix B of MIL-M-38510 and method 1005 of MIL-STD-883.

TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	---
Final electrical test parameters (method 5004)	1*, 2, 9
Group A test requirements (method 5005)	1, 2, 3, 4, 7, 9, 10, 11**
Groups C and D end-point electrical parameters (method 5005)	1, 2, 3
Additional electrical subgroups for group C periodic inspections	---

*PDA applies to subgroup 1.
**Subgroups 10 and 11, if not tested, shall be guaranteed to the specified limits in table I.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.

6.2 Replaceability. Replaceability is determined as follows:

a. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

b. When a QPL source is established, the part numbered device specified in this drawing will be replaced by the microcircuit identified as part number M38510/65307BXX.

6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

6.4 Approved sources of supply. Approved sources of supply are listed herein. Additional sources will be added as they become available. The vendors listed herein have agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor similar part number 1/	Replacement military specification part number
8407301EX 2/	04713 01295 27014 18714	54HC174/BEAJC SNJ54HC174J MM54CH174J/883B CD54HC174F/3A	M38510/65307BEX
8407301FX	01295	SNJ54HC174W	M38510/65307BFX
84073012X	04713 01295 27014	54HC174M/B2CJC SNJ54HC174FK MM54HC174E/883	M38510/65307B2X

1/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
2/ Inactive for new design. Use 38510/63507BEX.

Vendor CAGE number	Vendor name and address
04713	Motorola, Incorporated 7402 South Price Road Tempe, AZ 85283
01295	Texas Instruments, Incorporated P.O. Box 6448 Midland, TX 79701
27014	National Semiconductor P.O. Box 58090 Santa Clara, CA 95052-8090
18714	RCA Solid State Division Route 202 Somerville, NJ 08876